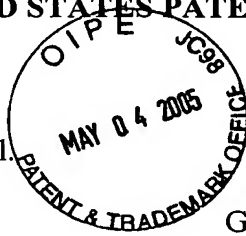


IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re patent application of

Masaki HASHIMURA, et al.



Serial No.: 10/601,310

Group Art Unit: 2812

Filing Date: June 23, 2003

Examiner: Unknown

For: SEMICONDUCTOR ELEMENT AND METHOD FOR PRODUCING THE SAME

INFORMATION DISCLOSURE STATEMENT

Sir:

Under the provisions of 37 CFR §1.97 through §1.99 and pursuant to Applicants' duty of disclosure under 37 CFR §1.56, Applicants respectfully bring the following documents cited in the Chinese Office Action and listed on the attached form PTO-1449, to the attention of the Examiner in charge of the above-identified application.

This citation does not constitute an admission that the references are relevant or material to the claims. They are only cited as constituting related art of which Applicants are aware.

In compliance with the concise explanation requirement under 37 CFR §1.98(a)(3) for foreign language documents, Applicants enclose herewith a copy of the Chinese Office Action citing such documents, together with an English-language version (if not already included) of the Search Report indicating the degree of relevance found by the foreign office. Further, English-language Abstracts are attached to the foreign references.

I hereby certify that each item of information contained in this Information Disclosure Statement was the first citation of that item by a foreign patent office in a counterpart foreign application, which occurred not more than three months prior to the filing of this statement.

Please charge any deficiencies in fees and credit any overpayment of fees to Attorney's Deposit Account No. 50-0481.

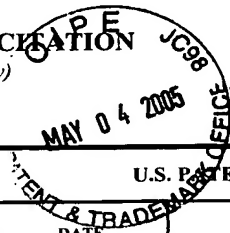
Respectfully submitted,

Sean M. McGinn  
Registration No. 34,386

Date: 5/4/05  
McGinn & Gibb, PLLC  
Intellectual Property Law  
8321 Old Courthouse Road, Suite 200  
Vienna, VA 22182-3817  
(703) 761-4100  
Customer No. 21254

# INFORMATION DISCLOSURE CITATION

(Use several sheets if necessary)



Docket Number (Optional) <b>T36-156800M/RS</b>		Application Number <b>10/601,310</b>
Applicant(s) <b>HASHIMURA, et al.</b>		
Filing Date <b>June 23, 2003</b>	Group Art Unit <b>2812</b>	

## U.S. PATENT DOCUMENTS

*EXAMINER INITIAL	REF	DOCUMENT NUMBER	DATE	NAME	CLASS	SUBCLASS	FILING DATE IF APPROPRIATE

## U.S. PATENT APPLICATION PUBLICATIONS

*EXAMINER INITIAL	REF	DOCUMENT NUMBER	DATE	NAME	CLASS	SUBCLASS	FILING DATE IF APPROPRIATE

## FOREIGN PATENT DOCUMENTS

REF	DOCUMENT NUMBER	DATE	COUNTRY	CLASS	SUBCLASS	Translation	
						YES	NO
	4-142760	05/15/1992	JAPAN			ABS	
	57-66650	04/22/1982	JAPAN			ABS	

## OTHER DOCUMENTS (Including Author, Title, Date, Pertinent Pages, Etc.)

Chinese Office Action dated April 1, 2005, with English Translation

EXAMINER

DATE CONSIDERED

EXAMINER: Initial if citation considered, whether or not citation is in conformance with MPEP Section 609; Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant.